# **TOSHIBA**

**TOSHIBA Original CMOS 16-Bit Microcontroller** 

TLCS-900 Series

**TMP96PM40** 

# **Preface**

Thank you very much for making use of Toshiba microcomputer LSIs. Before use this LSI, refer the section, "Points of Note and Restrictions". Especially, take care below cautions.

#### \*\*CAUTION\*\*

How to release the HALT mode

Usually, interrupts can release all halts status. However, the interrupts =  $(\overline{NMI}, INTO)$ , which can release the HALT mode may not be able to do so if they are input during the period CPU is shifting to the HALT mode (for about 3 clocks of X1) with IDLE or STOP mode. (In this case, an interrupt request is kept on hold internally.)

If another interrupt is generated after it has shifted to HALT mode completely, halt status can be released without difficultly. The priority of this interrupt is compare with that of the interrupt kept on hold internally, and the interrupt with higher priority is handled first followed by the other interrupt.

#### CMOS 16-bit Microcontrollers

#### TMP96PM40F

#### 1. Outline and Device Characteristics

TMP96PM40F is high-speed advanced 16-bit microcontrollers developed for controlling medium to large-scale equipment. The TMP96C141BF does not have a ROM, the TMP96CM40F has a built-in ROM of 32K-byte, and the TMP96PM40 has a built-in OTP of 32K-byte.

It is possible to do write / verify of program data with using a adapter socket and general purpose EPROM writer (TC571000 mode).

TMP96PM40 is pin compatible with TMP96CM40 (mask ROM type).

TMP96CM40F is housed in an 80-pin flat package.

Product name	ROM	RAM	Package	Adapter socket name
TMP96PM40F	OTP type 32 K×8 bit	1 K×8 bit	80-FP	BM1139A

For a discussion of how the reliability of microcontrollers can be predicted, please refer to Section 1.3 of the chapter entitled Quality and Reliability Assurance / Handling Precautions.

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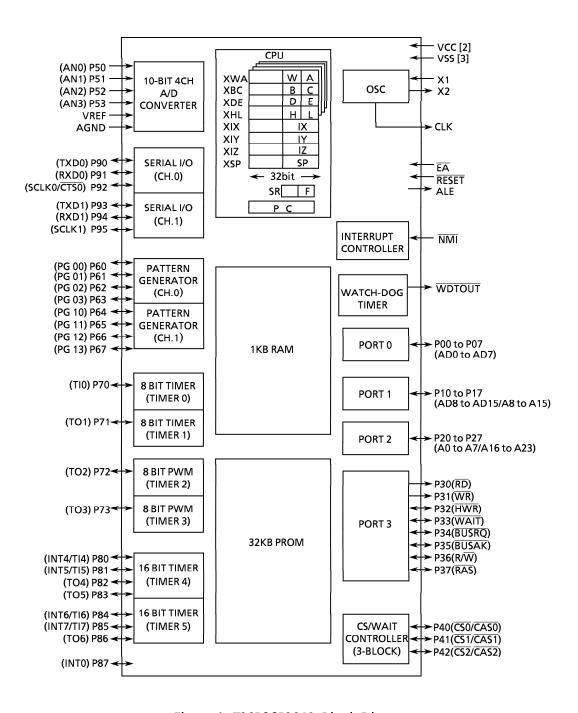


Figure 1 TMP96PM40 Block Diagram

# 2. Pin Assignment and Functions

The assignment of input / output pins for TMP96PM40, their name and outline functions are described below.

#### 2.1 Pin Assignment

Figure 2.1 shows pin assignment of TMP96PM40F.

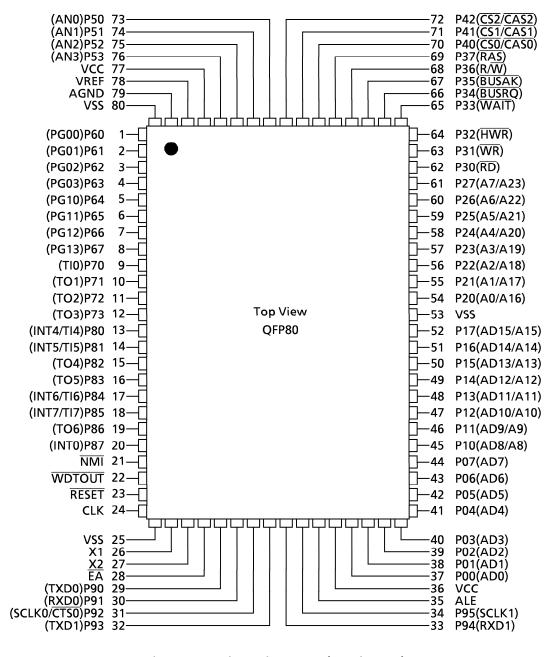


Figure 2.1 Pin Assignment (80-pin QFP)

# 2.2 Pin Names and Functions

TMP96PM40 has MCU mode and PROM mode.

The names of input/output pins and their functions are described below.

#### (1) MCU mode

Table 2.2 (1) Pin Names and Functions.

Pin name	Number of pins	I/O	Functions
P00 to P07 AD0 to AD7	8	I/O Tri-state	Port 0: I/O port that allows I/O to be selected on a bit basis Address/data (lower): 0 to 7 for address/data bus
P10 to P17 AD8 to AD15 A8 to A15	8	I/O Tri-state Output	Port 1: I/O port that allows I/O to be selected on a bit basis Address data (upper): 8 to 15 for address/data bus Address: 8 to 15 for address bus
P20 to P27 A0 to A7 A16 to A23	8	I/O Output Output	Port 2: I/O port that allows selection of I/O on a bit basis (with pull-down resistor) Address: 0 to 7 for address bus Address: 16 to 23 for address bus
P30 RD	1	Output Output	Port 30: Output port Read: Strobe signal for reading external memory
P31 WR	1	Output Output	Port 31: Output port Write: Strobe signal for writing data on pins AD0 to 7
P32 HWR	1	I/O Output	Port 32: I/O port (with pull-up resistor) High write: Strobe signal for writing data on pins AD8 to 15
P33 WAIT	1	I/O Input	Port 33: I/O port (with pull-up resistor) Wait: Pin used to request CPU bus wait
P34 BUSRQ	1	I/O Input	Port34: I/O port (with pull-up resistor) Bus request: Signal used to request high impedance for AD0 to 15, A0 to 23, RD, WR, HWR, R/W, RAS, CSO, CS1, and CS2 pins. (For external DMAC)
P35 BUSAK	1	I/O Output	Port 35: I/O port (with pull-up resistor) Bus acknowledge: Signal indicating that AD0 to 15, A0 to 23, RD, WR, HWR, R/W, RAS, CSO, CS1, and CS2 pins are at high impedance after receiving BUSRQ. (For external DMAC)
P36 R/W	1	I/O Output	Port 36: I/O port (with pull-up resistor) Read/write: 1 represents read or dummy cycle; 0, write cycle.
P37 RAS	1	I/O Output	Port 37: I/O port (with pull-up resistor) Row address strobe: Outputs RAS strobe for DRAM.
P40 CS0	1	I/O Output	Port 40: I/O port (with pull-up resistor) Chip select 0: Outputs 0 when address is within specified address area.
CAS0		Output	Column address strobe 0: Outputs CAS strobe for DRAM when address is within specified address area.

Note: With the external DMA controller, this device's built-in memory or built-in I/O cannot be accessed using the  $\overline{BUSRQ}$  and  $\overline{BUSAK}$  pins.

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Pin name	Number of pins	I/O	Functions
P41 CS1 CAS1	1	I/O Output Output	Port 41: I/O port (with pull-up resistor) Chip select 1: Outputs 0 if address is within specified address area. Column address strobe 1: Outputs CAS strobe for DRAM if address is within specified address area.
P42 CS2 CAS2	1	I/O Output Output	Port 42: I/O port (with pull-down resistor) (Note) Chip select 2: Outputs 0 if address is within specified address area. Column address strobe 2: Outputs CAS strobe for DRAM if address is within specified address area.
P50 to P53 AN0 to AN3	4	Input Input	Port 5: Input port Analog input: Input to A/D converter
VREF	1	Input	Pin for reference voltage input to A/D converter
AGND	1	Input	Ground pin for A/D converter
P60 to P63 PG00 to PG03	4	I/O Output	Ports 60 to 63: I/O ports that allow selection of I/O on a bit basis (with pull-up resistor)  Pattern generator ports: 00 to 03
P64 to P67 PG10 to PG13	4	I/O Output	Ports 64 to 67: I/O ports that allow selection of I/O on a bit basis (with pull-up resistor) Pattern generator ports: 10 to 13
P70 TI0	1	I/O Input	Port 70: I/O port (with pull-up resistor) Timer input 0: Timer 0 input
P71 TO1	1	I/O Output	Port 71: I/O port (with pull-up resistor) Timer output 1: Timer 0 or 1 output
P72 TO2	1	I/O Output	Port 72: I/O port (with pull-up resistor) PWM output 2: 8-bit PWM timer 2 output
P73 TO3	1	I/O Output	Port 73: I/O port (with pull-up resistor) PWM output 3: 8-bit PWM timer 3 output
P80 TI4 INT4	1	I/O Input Input	Port 80: I/O port (with pull-up resistor) Timer input 4: Timer 4 count/capture trigger signal input Interrupt request pin 4: Interrupt request pin with programmable rising/falling edge
P81 TI5 INT5	1	I/O Input Input	Port 81: I/O port (with pull-up resistor) Timer input 5: Timer 4 count/capture trigger signal input Interrupt request pin 5: Interrupt request pin with rising edge
P82 TO4	1	I/O Output	Port 82: I/O port (with pull-up resistor) Timer output 4: Timer 4 output pin
P83 TO5	1	I/O Output	Port 83: I/O port (with pull-up resistor) Timer output 5: Timer 4 output pin

Note: Case of the settable  $\overline{\text{CS2}}$  or  $\overline{\text{CAS2}}$ ; when TMP96PM40F is bus release, this pin is not added the internal pull-down resistor but is added the internal pull-up resistor.

Pin name	Number of pins	I/O	Functions
P84 TI6 INT6	1	I/O Input Input	Port 84: I/O port (with pull-up resistor) Timer input 6: Timer 5 count/capture trigger signal input Interrupt request pin 6: Interrupt request pin with programmable rising/falling edge
P85 TI7 INT7	1	l/O Input Input	Port 85: I/O port (with pull-up resistor) Timer input 7: Timer 5 count/capture trigger signal input Interrupt request pin 7: Interrupt request pin with rising edge
P86 TO6	1	I/O Output	Port 86: I/O port (with pull-up resistor) Timer output 6: Timer 5 output pin
P87 INT0	1	I/O Input	Port 87: I/O port (with pull-up resistor) Interrupt request pin 0: Interrupt request pin with programmable level/rising edge
P90 TXD0	1	I/O Output	Port 90: I/O port (with pull-up resistor) Serial send data 0
P91 RXD0	1	I/O Input	Port 91: I/O port (with pull-up resistor) Serial receive data 0
P92 CTS0 SCLK0	1	I/O Input I/O	Port 92: I/O port (with pull-up resistor) Serial data send enable 0 (Clear to Send) Serial clock I/O 0
P93 TXD1	1	I/O Output	Port 93: I/O port (with pull-up resistor) Serial send data 1
P94 RXD1	1	I/O Input	Port 94: I/O port (with pull-up resistor) Serial receive data 1
P95 SCLK1	1	I/O I/O	Port 95: I/O port (with pull-up resistor) Serial clock I/O 1
WDTOUT	1	Output	Watchdog timer output pin
NMI	1	Input	Non-maskable interrupt request pin: Interrupt request pin with falling edge. Can also be operated at rising edge by program.
CLK	1	Output	Clock output: Outputs 「X1 ÷ 4 」 clock. Pulled-up during reset.
ĒĀ	1	Input	External access: 0 should be inputted with TMP96C141B. 1, with TMP96CM40 / TMP96PM40.
ALE	1	Output	Address latch enable
RESET	1	Input	Reset: Initializes LSI. (With pull-up resistor)
X1/X2	2	I/O	Oscillator connecting pin
vcc	2		Power supply pin ( $\pm$ 5 V) (All Vcc pins should be connected with the power supply pin.)
VSS	3		GND pin (0 V) (All Vss pins should be connected with GND (0 V).)

Note: Pull-up/pull-down resistor can be released from the pin by software (except the  $\overline{RESET}$  pin).

# (2) PROMmode

Table 2.2 (2) Name and function of PROM mode

Pin function	Pin number	Input / Output	Function	Pin name (MCU mode)				
A7 to A0	8	Input		P27 to P20				
A15 to A8	8	Input	Memory address of program	P17 to P10				
A16	1	Input		P33				
D7 to D0	8	I/O	Memory data of pfogram	P07 to P00				
CE	1	Input	Chip enable	P32				
ŌĒ	1	Input	Output control	P30				
PGM	1	Input	Program control	P31				
VPP	1	Power supply Power	12.75 V / 5 V (Power supply of program)	ĒΑ				
vcc	2	Power supply Power	6.25 V / 5 V	VCC				
vss	3	Power supply	0 V	VSS				
Pin function	Pin number	Input / Output	Disposal of pir					
P34	1	Input	Fix to low level (security pin)					
RESET	1	Input	Fix to low level (PROM mode)					
CLK	1	Input	Fix to low level (FROM Mode)					
ALE	1	Output	Open					
X1	1	Input	- Crystal					
X2	1	Output	Crystal					
P95 to P94, VREF	3	Input	Fix to high level					
AGND	1	Input	ov					
P37 to P35								
P42 to P40								
P53 to P50								
P67 to P60								
P73 to P70	36	I/O	open					
P87 to P80								
<mark>NМ</mark> Ī,								
WDTOUT								
P93 to P90								

# 3. Operation

This section describes the hardware and basic operation of TMP96PM40 device. TMP96PM40 is exchanged mask ROM of TMP96CM40 for PROM. The other specifications and functions are the same as TMP96CM40.

Check the \[ \begin{aligned} 7. Care Points and Restriction of TMP96C141B \] because of the Care described. Regarding the function of TMP96PM40 (not described), see the part of TMP96CM40 for ports functions and bus release functions, and see the part of TMP96C141B for other functions.

The operation modes are MCU mode and PROM mode.

TMP96C141B/TMP96CM40/TMP96PM40 have much the same function but they are different from following points.

Parameter	TMP96C141B TMP96CM40		TMP96PM40		
Interrnal ROM	Not exist	Mask ROM32 Kbyte	PROM32 Kbyte		
P00 to P07, AD0 to AD7	Only AD0 to AD7	After reset P00 to P07			
P10 to P17, AD8 to AD15, A8 to A15	Only AD8 to AD15	After reset P10 to P17			
P30, RD	Only RD	After re	set P30		
P31, WR	Only WR	After reset P31			
Pin state at the bus release	TMP96C141B see Table 3.5 (1)	TMP96CM40 see Table 3.3 (1)			

#### 3.1 MCU mode

#### (1) Mode-setting and function

The MCU mode is set by opening the CLK pin (Output status).

In the MCU mode, the operation is same as that of TMP96CM40.

#### (2) Memory Map

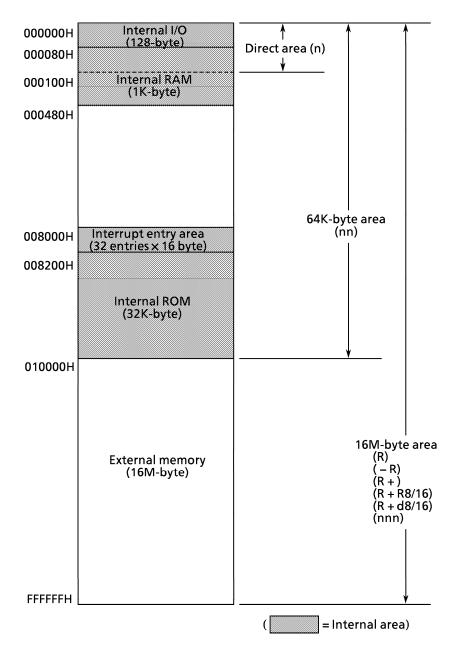
The memory map of TMP96PM40 is same as that of TMP96CM40.

Figure 3.1 shows the memory map of TMP96PM40, and the accessing area by the respective addressing mode.

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#### **Memory Map**

Figure 3.1 is a memory map of the TMP96CM40.



Note: The start address after reset is 8000H. Resetting sets the stack pointer (XSP) on the system mode side to 100H.

Figure 3.1 Memory map

# 4. Electrical Characteristics

# 4.1 Absolute Maximum Ratings (TMP96PM40)

Parameter	Symbol	Rating	Unit
Power Supply voltage	V cc	– 0.5 to 6.5	V
Input voltage	VIN	- 0.5 to Vcc + 0.5	V
Output Current (total)	ΣIOL	100	mA
Output Current (total)	ΣΙΟΗ	- 100	mA
Power Dissipation (Ta = $70^{\circ}$ C)	PD	500	mW
Soldering Temperature (10 s)	T SOLDER	260	°C
Storage temperature	T STG	– 65 to 150	${\mathfrak C}$
Operating temperature	T OPR	– 40 to 85	င

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

### 4.2 DC Characteristics (TMP96PM40)

 $Vcc = 5 V \pm 10\%$ , TA = -20 to 70% (4 to 20 MHz) TA = -40 to 85% (4 to 16 MHz) (Typical values are for Ta = 25% and Vcc = 5 V.)

Parameter	Symbol	Test Condition	Min	Max	Unit
Input Low Voltage (AD0 to 15) P2, P3, P4, P5, P6, P7, P8, P9 RESET, NMI, INTO(P87) EA X1	VIL VIL1 VIL2 VIL3 VIL4		-0.3 -0.3 -0.3 -0.3 -0.3	0.8 0.3 Vcc 0.25 Vcc 0.3 0.2 Vcc	>>>>
Input High Voltage (AD0 – 15) P2, P3, P4, P5, P6, P7, P8, P9 RESET, NMI, INTO (P87) EA X1	VIH VIH1 VIH2 VIH3 VIH4		2.2 0.7 Vcc 0.75 Vcc Vcc – 0.3 0.8 Vcc	Vcc + 0.3 Vcc + 0.3 Vcc + 0.3 Vcc + 0.3 Vcc + 0.3	>>>>>
Output Low Voltage	V OL	I OL = 1.6 mA		0.45	V
Output High Voltage	V OH V OH1 V OH2	I OH = - 400 μA I OH = - 100 μA I OH = - 20 μA	2.4 0.75 Vcc 0.9 Vcc		>>>
Darlington Drive Current (8 Output Pins max.)	IDAR	V EXT = 1.5 V R EXT = 1.1 kΩ	<b>–</b> 1.0	- 3.5	mΑ
Input Leakage Current Output Leakage Current	I LI I LO	0.0≦ Vin≦ Vcc 0.2≦ Vin≦ Vcc – 0.2	0.02 (Typ) 0.05 (Typ)	±5 ±10	μ <b>Α</b> μ <b>Α</b>
Operating Current (RUN) IDLE STOP (Ta = −40 to 85°C) STOP (Ta = 0 to 50°C)	l cc	fc = 20 MHz 0.2 ≤ Vin ≤ Vcc - 0.2 0.2 ≤ Vin ≤ Vcc - 0.2	30 (Typ) 2.0 (Typ) 0.2 (Typ)	60 10 50 10	mA mA μA μA
Power Down Voltage (@ STOP, RAM Back up)	V STOP	V IL2 = 0.2 Vcc, V IH2 = 0.8 Vcc	2.0	6.0	٧
RESET Pull Up Resistor	R RST		50	150	<b>k</b> Ω
Pin Capacitance	CIO	fc = 1 MHz		10	pF
Schmitt Width RESET, NMI, INTO (P87)	VTH		0.4	1.0 (Typ)	V
Programmable Pull Down Resistor	R KL		10	80	kΩ
Programmable Pull Up Resistor	R KH		50	150	<b>k</b> Ω

Note: I-DAR is guaranteed for a total of up to 8 ports.

### 4.3 AC Electrical Characteristics (TMP96PM40)

 $Vcc = 5 V \pm 10\% TA = -40 to 85 °C (4 to 16 MHz), TA = -20 to 70 °C (4 to 20 MHz)$ 

No.	Paramerer S		Vari	able	16 N	/lHz	20 N	Unit	
NO.	raramerer	Symbol	Min	Max	Min	Max	Min	Max	Unit
1	Osc. Period ( = x)	tosc	50	250	62.5		50		ns
2	CLK width	t <sub>CLK</sub>	2x – 40		85		60		ns
3	A0 to 23 Valid → CLK Hold	t <sub>AK</sub>	0.5x - 20		11		5		ns
4	CLK Valid → A0 to 23 Hold	t <sub>KA</sub>	1.5x - 70		24		5		ns
5	A0 to 15 Valid → ALE fall	t <sub>AL</sub>	0.5x - 15		16		10		ns
6	ALE fall → A0 to 15 Hold	t <sub>LA</sub>	0.5x - 15		16		10		ns
7	ALE High width	t <sub>LL</sub>	x – 40		23		10		ns
8	ALE fall → RD/WR fall	t <sub>LC</sub>	0.5x - 30		1		-5		ns
9	RD/WR rise → ALE rise	t <sub>CL</sub>	0.5x - 20		11		5		ns
10	A0 to 15 Valid $\rightarrow \overline{RD}/\overline{WR}$ fall	t <sub>ACL</sub>	x – 25		38		25		ns
11	A0 to 23 Valid $\rightarrow \overline{RD}/\overline{WR}$ fall	t <sub>ACH</sub>	1.5x - 50		44		25		ns
12	RD/WR rise → A0 to 23 Hold	tca	0.5x - 20		11		5		ns
13	A0 to 15 Valid $\rightarrow$ D0 to 15 input	t <sub>ADL</sub> *		3.0x – 55		133		95	ns
14	A0 to 23 Valid $\rightarrow$ D0 to 15 input	t <sub>ADH</sub>		3.5x – 65		154		110	ns
15	RDfall → D0 to 15 input	t <sub>RD</sub>		2.0x – 50		75		50	ns
16	RD Low width	t <sub>RR</sub>	2.0x - 40		85		60		ns
17	RDrise → D0 to 15 Hold	t <sub>HR</sub>	0		0		0		ns
18	RDrise → A0 to 15output	t <sub>RAE</sub>	x – 15		48		35		ns
	WR Low width	tww	2.0x - 40		85		60		ns
20	D0 to 15 Valid $\rightarrow \overline{WR}$ rise	$t_{\sf DW}$	2.0x - 50		75		50		ns
21		t <sub>WD</sub>	0.5x - 10		21		15		ns
22	A0 to 23 Valid $\rightarrow \overline{\text{WAIT}}$ input $\binom{1\text{WAIT}}{+ \text{n mode}}$	t <sub>AEH</sub>		3.5x – 90		129		85	ns
23	A0 to 15 Valid $\rightarrow \overline{\text{WAIT}}$ input $\binom{1\text{WAIT}}{+ \text{n mode}}$	t <sub>AWL</sub>		3.0x - 80		108		70	ns
24	$\overline{RD/WR}$ fall $\rightarrow \overline{WAIT}$ Hold $\binom{1WAIT}{+ \text{n mode}}$	tcw	2.0x + 0		125		100		ns
25	A0 to 23 Valid → PORT input	t <sub>APH</sub>		2.5x – 120		36		5	ns
26	A0 to 23 Valid → PORT Hold	t <sub>APH2</sub>	2.5x + 50		206		175		ns
27	WR rise → PORT Valid	t <sub>CP</sub>		200		200		200	ns
28	A0 to 23 Valid $\rightarrow \overline{RAS}$ fall	tasrh	1.0x - 40		23		10		ns
	A0 to 15 Valid $\rightarrow \overline{RAS}$ fall	t <sub>ASRL</sub>	0.5x - 15		16		10		ns
30	$\overline{RAS}$ fall $\rightarrow$ D0 to 15 input	t <sub>RAC</sub>		2.5x – 70		86		55	ns
31	$\overline{RAS}$ fall $\rightarrow$ A0 to 15 Hold	$t_{RAH}$	0.5x - 15		16		10		ns
32	RAS Low width	t <sub>RAS</sub>	2.0x - 40		85		60		ns
33	RAS High width	t <sub>RP</sub>	2.0x - 40		85		60		ns
34	CAS fall → RAS rise	t <sub>RSH</sub>	1.0x - 35		28		15		ns
	RAS rise → CAS rise	t <sub>RSC</sub>	0.5x - 25		6		0		ns
	RAS fall → CAS fall	t <sub>RCD</sub>	1.0x - 40		23		10		ns
37	$\overline{CAS}$ fall $\rightarrow$ D0 to 15 input	t <sub>CAC</sub>		1.5x – 65		29		10	ns
38	CAS Low width	tcas	1.5x - 30		64		40		ns
			_						

<sup>\*</sup> t<sub>ADL</sub> value is different from TMP96C141B/TMP96CM40.

#### **AC Measuring Conditions**

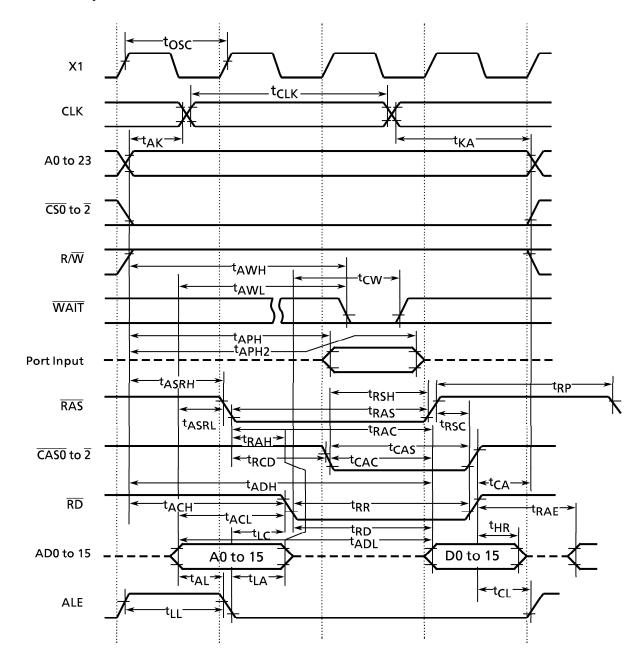
Output Level : High 2.2 V / Low 0.8 V , CL50 pF

(However CL = 100 pF for AD0 to AD15, A0 to A23, ALE, RD, WR, HWR, R/W, CLK, RAS, CAS0 to CAS2)

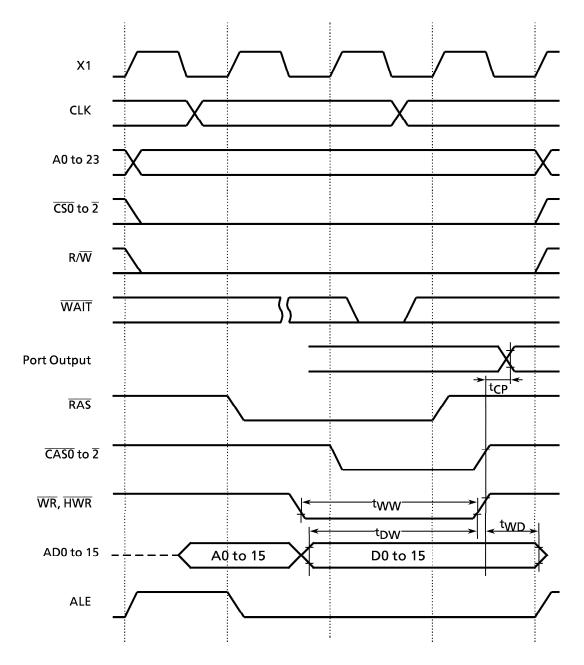
• Input Level : High 2.4V / Low 0.45V (AD0 to AD15)

High 0.8Vcc/Low 0.2Vcc (Except for AD0 to AD15)

# (1) Read Cycle



# (2) Write Cycle



#### 4.4 A/D Conversion Characteristics (TMP96PM40)

 $Vcc = 5 V \pm 10\%$  TA = -40 to 85°C (4 to 16 MHz) TA = -20 to 70°C (4 to 20 MHz)

	Parameter	Symbol	Min	Тур.	Max	Unit
Analog reference	e voltage	V <sub>REF</sub>	Vcc – 1.5		Vcc	
Analog reference voltage		A <sub>GND</sub>	Vss		Vss	v
Analog input vol	tage range	V <sub>AIN</sub>	Vss		Vcc	
Anlog current fo	Anlog current for analog reference voltage			0.5	1.5	mA
4 < 5 < 4 C DALL	Low change mode	Total		± 1.5	± 4.0	
4≦ fc≦ 16 MHz	High change mode	error(Quantize error of ± 0.5		± 3.0	± 6.0	
15 45 20 NAU-	Low change mode	LSB not included)		± 1.5	± 4.0	LSB
16 <fc≦ 20="" mhz<="" td=""><td>High change mode</td><td>meradeay</td><td></td><td>± 4.0</td><td>± 8.0</td><td></td></fc≦>	High change mode	meradeay		± 4.0	± 8.0	

#### 4.5 Serial Channel Timing – I/O Interface Mode

#### (1) SCLK Input Mode Vcc = 5 V

 $Vcc = 5 V \pm 10\% TA = -40 to 85^{\circ}C (4 to 16 MHz)$   $TA = -20 to 70^{\circ}C (4 to 20 MHz)$ 

Parameter	Symbol	Variable		16 MHz		20 MHz		Unit	
	Symbol	Min	Max	Min	Max	Min	Max	Unit	
SCLK cycle	t <sub>SCY</sub>	16X		1		0.8		$\mu$ S	
Output Data $\rightarrow$ Rising edge of SCLK	toss	t <sub>SCY</sub> /2 – 5X – 50		137		100		ns	
SCLK rising edge→ Output Data hold	t <sub>OHS</sub>	5X – 100		212		150		ns	
SCLK rising edge→ Input Data hold	t <sub>HSR</sub>	0		0		0		ns	
SCLK rising edge→effective data input	t <sub>SRD</sub>		t <sub>SCY</sub> – 5X – 100		587		450	ns	

### (2) SCLK Output Mode $Vcc = 5 V \pm 10\% TA = -40 \text{ to } 85^{\circ}\text{C} \text{ (4 to } 16 \text{ MHz)} \quad TA = -20 \text{ to } 70^{\circ}\text{C} \text{ (4 to } 20 \text{ MHz)}$

Daniero esteri	C. mala al	Variable		16 MHz		20 MHz		l lmit	
Parameter	Symbol	Min	Max	Min	Max	Min	Max	Unit	
SCLK cycle (programmable)	t <sub>SCY</sub>	16X	8192X	1	512	0.8	409.6	μS	
Output Data → SCLK rising edge	toss	t <sub>SCY</sub> – 2X – 150		725		550		ns	
SCLK rising edge→ Output Data hold	t <sub>OHS</sub>	2X – 80		45		20		ns	
SCLK rising edge→Input Data hold	t <sub>HSR</sub>	0		0		0		ns	
SCLK rising edge → effective data input	t <sub>SRD</sub>		t <sub>SCY</sub> – 2X – 150		725		550	ns	

## 4.6 Timer/Counter Input Clock (TI0, TI4, TI5, TI6, TI7)

 $Vcc = 5 V \pm 10\%$  TA = -40 to 85°C (4 to 16 MHz) TA = -20 to 70°C (4 to 20 MHz)

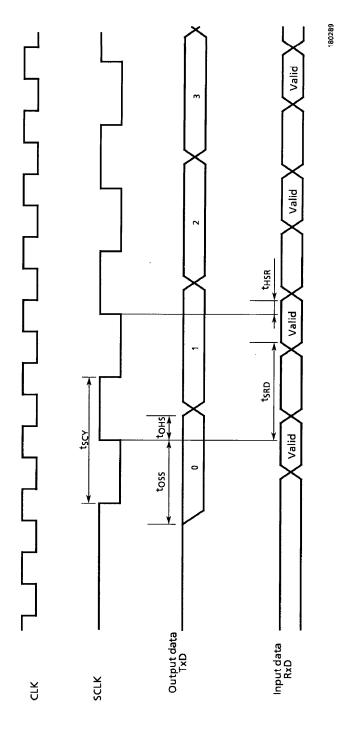
Devemates	C. mala al	Varia	16 MHz		20 MHz		l l mia	
Parameter	Symbol	Min	Max	Min	Max	Min	Max	Unit
Clock Cycle	t <sub>VCK</sub>	8X + 100		600		500		ns
Low level clock Pulse width	t <sub>VCKL</sub>	4X + 40		290		240		ns
High level clock Pulse width	t <sub>VCKH</sub>	4X + 40		290		240		ns

#### 4.7 Interrupt Operation

 $Vcc = 5 V \pm 10\%$  TA = -40 to 85°C (4 to 16 MHz) TA = -20 to 70°C (4 to 20 MHz)

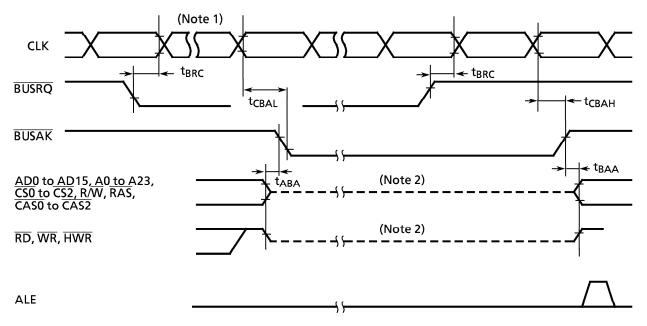
Parameter	Symbol	Varia	16 MHz		20 MHz		Unit	
Farameter	Symbol	Min	Max	Min	Max	Min	Max	Onit
NMI, INTO Low level Pulse width	t <sub>INTAL</sub>	4X		250		200		ns
NMI, INTO High level Pulse width	t <sub>INTAH</sub>	4X		250		200		ns
INT4 to INT7 Low level Pulse width	t <sub>INTBL</sub>	8X + 100		600		500		ns
INT4 to INT7 High level Pulse width	t <sub>INTBH</sub>	8X + 100		600		500		ns

# 4.8 Timing Chart for I/O Interface Mode



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#### Timing Chart for Bus Request (BUSRQ) / BUS Acknowledge (BUSAK) 4.9



Parameter	Symbol	Variable		16 MHz		20 MHz		l l m l t
		Min	Max	Min	Max	Min	Max	Unit
BUSRQ set-up time for CLK	t <sub>BRC</sub>	120		120		120		ns
CLK→ BUSAK falling edge	t <sub>CBAL</sub>		1.5x + 120		214		195	ns
CLK→ BUSAK rising edge	t <sub>CBAH</sub>		0.5x + 40		71		65	ns
Output Buffer is off to BUSAK	t <sub>ABA</sub>	0	80	0	80	0	80	ns
BUSAK to Output Buffer is on.	t <sub>BAA</sub>	0	80	0	80	0	80	ns

Note 1: The Bus will be released after the WAIT request is inactive, when the BUSRQ is set to "0" during "Wait" cycle.

Note 2: This line only shows the output buffer is off-state.

They don't indicate the signal level is fixed.

After the bus is released, the signal level is kept dynamically before the bus is released by the external capacitance.

Therefore to fix the signal level by an external registence under the bus is releasing the

Therefore, to fix the signal level by an external resistance under the bus is releasing, the design must be carefully because of the level-fix will be delayed.

The internal programmable pull-up/pull-down resistance is switched active/non-active by the internal signal.

# 4.10 Read Operation (PROM Mode)

# DC Characteristic, AC Characteristic

 $TA = -40 \text{ to } 85^{\circ}C \text{ Vcc} = 5 \text{ V} \pm 10\%$ 

Parameter	Symbol	Condition	Min	Max	Unit
V <sub>PP</sub> Read Voltage Input High Voltage (A0 to A16, $\overline{\text{CE}}$ , $\overline{\text{OE}}$ , $\overline{\text{PGM}}$ ) Input Low Voltage (A0 to A16, $\overline{\text{CE}}$ , $\overline{\text{OE}}$ , $\overline{\text{PGM}}$ )	V <sub>PP</sub> V <sub>IH1</sub> V <sub>IL1</sub>	- - -	4.5 0.7×V <sub>CC</sub> -0.3	5.5 V <sub>CC</sub> + 0.3 0.3 × V <sub>CC</sub>	> > >
Address to Output Delay	t <sub>ACC</sub>	C <sub>L</sub> = 50 <sub>P</sub> F	_	2.25 TCYC + α	ns

TCYC = 400 ns (10 MHz Clock)  $\alpha$  = 200 ns

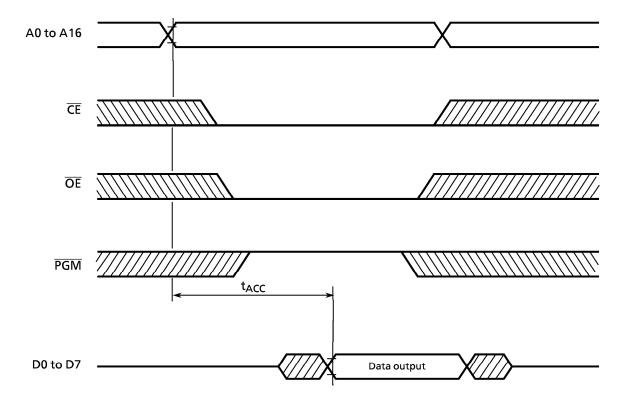
# 4.11 Programming Operation (PROM Mode)

# DC Characteristic, AC Characteristic

 $TA = 25 \pm 5^{\circ}C \ Vcc = 6.25 \ V \pm 0.25 \ V$ 

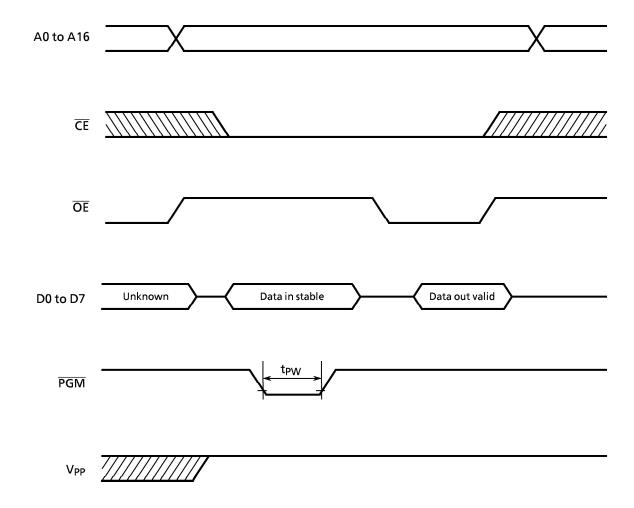
Parameter	Symbol	Condition	Min	Тур.	Max	Unit
Programing Supply Voltage Input High Voltage (D0 to D7) Input Low Voltage (D0 to D7) Input High Voltage (A0 to A16, $\overline{CE}$ , $\overline{OE}$ , $\overline{PGM}$ ) Input Low Voltage (A0 to A16, $\overline{CE}$ , $\overline{OE}$ , $\overline{PGM}$ ) V <sub>CC</sub> Supply Current V <sub>PP</sub> Supply Current	V <sub>PP</sub> V <sub>IH</sub> V <sub>IL</sub> V <sub>IH1</sub> V <sub>IL1</sub> I <sub>CC</sub> I <sub>PP</sub>	- - - - fc = 10 MHz V <sub>PP</sub> = 13.00 V	12.50 0.2V <sub>CC</sub> + 1.1 - 0.3 0.7V <sub>CC</sub> - 0.3 - -	12.75	13.00 V <sub>CC</sub> + 0.3 0.2V <sub>CC</sub> -0.1 V <sub>CC</sub> + 0.3 0.3V <sub>CC</sub> 50 50	V V V V mA mA
PGM Program Pulse Width	t <sub>PW</sub>	C <sub>L</sub> = 50 <sub>P</sub> F	0.095	0.1	0.105	ms

# 4.12 Read Operation Timing Chart (PROM Mode)



## 4.13 Programming Operation Timing Chart (PROM Mode)

High Speed Program Writing.



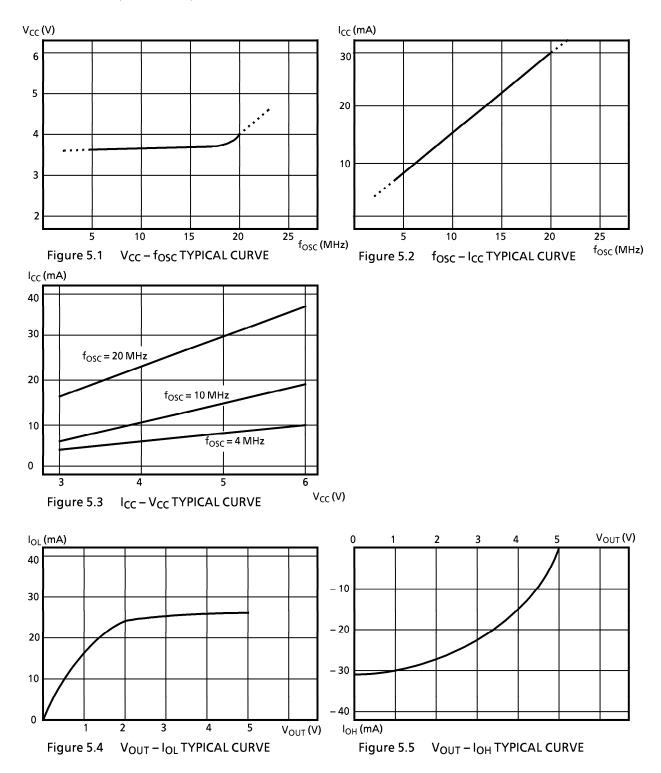
Note 1: The power supply of  $V_{PP}$  (12.75 V) must be set power-on at the same time or the later time for a power supply of  $V_{CC}$  and must be clear power-on at the same time or early time for a power supply of  $V_{CC}$ .

Note 2: The pulling up/down device on condition of  $V_{PP} = 12.75 \text{ V}$  suffer a damage for the device.

Note 3: The maximum spec of VPP pin is 14.0 V. Be carefull a overshoot at the program writing.

### 4.14 Typical Characteristics

Vcc=5 V, Ta=25°C, Unless otherwise noted.



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